Microcontroller interface to configure HO transducer

1. Introduction

This document aims to describe the programming function of HO series current transducer.

2. ASIC Description

2.1 Overview

HO series current transducer has ASIC (Application Specific Integrated Circuit) with EEPROM, and operates according to the setting data loaded from the EEPROM at power-ON. You can select sensitivity (gain), reference voltage (V_{col}) , output filter setting, and so on by changing the data in EEPROM or RAM using serial communication.

2.2 ASIC Configuration **EEPROM**

The EEPROM loaded in ASIC consists of 32 words (16bits x 32).

Address (EEPROM)	[15]
00	Х
•	•
•	•
•	•
26	Х
27	Х
28	X
29	
30	
31	

ess	Data (16 bits)															
OM)	[15]		ſ	14:10]		[9:5]					[4:0]				
,	(lock bit)		(settin	g data :	5bits)			(settin	g data :	5bits)			(settin	g data :	5bits)	
	Χ	D4	D3	D2	D1	D0	D4	D3	D2	D1	D0	D4	D3	D2	D1	D0
	•															
	•															
	•															
	Х	D424	D133	D422	D131	D130	D134	D133	D422	D131	D420	D134	D133	D132	D424	D130
		D134				D130	D134				טוט	D134				D130
	X	CRC-10 [4:0]					CRC-10 [4:0] CRC-10 [4:0]									
	Χ	X CRC-10 [9:5]					CRC-10 [9:5]			CRC-10 [9:5]						
							Re	ead C	nly							

Table 2.1 EEPROM Address Map

 Address 	$00\sim26$: ASIC setting data
 Address 	$27 \sim 28$: CRC-10 (Check data)
 Address 	$29 \sim 31$: ASIC ID (Read Only)

ASIC setting data

To reduce a risk of incorrect operation by loss of memory data due to exogenous noise and so on, this ASIC operates by the majority vote data of 3 setting data which are stored in the EEPROM.

3 setting data are originally the same and they are divided in every 5 bits. The ASIC copies the majority vote data to the ROM when it is powered ON.

For example, the value of 'D0' is stored in address '00' at [0]bit (LSB), [5]bit, and [10]bit. ASIC reads the 3 data, and if more

Contents Introduction **ASIC** Description Overview 2.2 ASIC Configuration 3 3.1 Serial communication 6 Overview Timing chart Command list 3.4 Communication Procedure Implementation example 9 on Arduino Overview 9 10 **Schematics** 10 Sample program 4.3.1 List of sample program 10 4.3.2 List of parameters and functions 12 4.3.3 Explanation of sample program: sensorPTC 15 16 **Appendix** HO 25-NPPR Initial value of setting parameters



ASIC Description

than two data are "1", ASIC will copy "1" to the ROM as the value of 'D0'. Therefore, it is required to write same value into each 5 bits which are [4:0]bits, [9:5]bits, and [14:10]bits in the 16bits when you write a data to EEPROM.

Change of the EEPROM data will be applied at the next power-ON. If you need to change the current transducer operation immediately, you should change the ROM data.

CRC-10

CRC-10 is the check data called Cyclic Redundancy Check and it is defined by the standard ITU-T (International Telecommunication Union Telecommunication Standardization Sector) 1.610.

You need to update the CRC value by defined computation method and write into the memory whenever you change the memory data. You should write same value into each 5 bits as previously described when you change the EEPROM data (See "ComputeCRC10" and "UpdateCRC10" function in the sample program).

The polynomial of CRC-10 : $x^{10} + x^9 + x^5 + x^4 + x + 1$ (11000110011)

The ASIC re-computes the value of CRC-10 from all of the setting data in the EEPROM and compares the computed data with the CRC-10 data stored in the address 27 and 28 at power-ON. If there is a difference between the two CRC-10 data, ASIC determines there is a defect at EEPROM data, and the output of HO series current transducer (V_{out}) is forced to 0V (at ARF = 1 setting).

ASIC ID

ASIC ID is a unique production number of the ASIC and it cannot be modified.

The RAM loaded in ASIC consists of 5bits x 28.

Table 2.2: RAM address Map Address (RAM) 26 27

28

Data (5bits)					
[4:0] (setting data : 5bits)					
D4	D3	D2	D1	D0	
D134 D133 D132 D131 D130					
CRC-10 [4:0]					
	CR	C-10	[9:5]		

The ASIC behaves on the setting data in the ROM while the ASIC is power-ON. And you can change the operation of current transducer by changing the data in the ROM. The data stored in ROM will disappear when the ASIC is powered OFF, and setting data will be copied from EEPROM at every powered ON. Therefore, you need to change the EEPROM data also if you need to keep the setting after you power off the current transducer. On the other hand, you can restore the default setting at every power-ON if you only change the ROM setting data.

ASIC Description

ASIC setting parametes

HO-NPPR Application Note

The following table and description shows the seting parameters (EEPROM memory map) and each behaviour.

[4] [13] [8] [3] [12]	[4] [13] [8] [3] [12]	(13) [8] [3] [12]	DATA (8) (3) (12)	DAT,	DAT,	F I		A bit	[2]	[11]	[6]	[1]	[10]	[5]	[0]
		GA[4] (D4) GA[9] (D9)			GA[8] (D3) GA[8] (D8)			GA[2] (D2) GA[7] (D7)			GA[1] (D1) GA[6] (D6)			GA[0] (D0) GA[5] (D5)	
		GB[2] (D14)			GB[1] (D13)			GB[0] (D12)		0	3A[11] (D11))	GA[10] (D10)	
		GB[7] (D19)			GB[6] (D18)			GB[5] (D17))	GB[4] (D16)			GB[3] (D15)	
		GC[0] (D24)		9	GB[11] (D23)		9	GB[10] (D22))	GB[9] (D21)			GB[8] (D20)	
		GC[5] (D29)			GC[4] (D28)			GC[3] (D27))	GC[2] (D26)			GC[1] (D25)	
	9	GC[10] (D34)			GC[9] (D33)			GC[8] (D32))	GC[7] (D31)			GC[6] (D30)	
	RES	RESERVED (D39)	39)	RE	RESERVED (D38)	38)	RES	RESERVED (D37)	17)	RES	RESERVED (D36)	36)	0	GC[11] (D35)	
		DVR (D44)			RS[1] (D43)			RS[0] (D42)		S	SGE[1] (D41)		0)	SGE[0] (D40)	
	0)	STE[2] (D49)		0)	STE[1] (D48)		0)	STE[0] (D47)		3,	SF[1] (D46)			SF[0] (D45)	
	TC	TCCOLD[3] (D54)	(4)	TC	TCCOLD[2] (D53)	53)		TSS (D52)			TDT (D51)			ARF (D50)	
	L.	RTA[1] (D59)		Ľ.	RTA[0] (D58)		RES	RESERVED (D57)	(25	RES	RESERVED (D56)	99)	RE	RESERVED (D55))
\Box	Υ .	RTC[0] (D64)		4	RTB[2] (D63)		<u> </u>	RTB[1] (D62)		R	RTB[0] (D61)		H	RTA[2] (D60)	
\Box	ъ.	RTD[2] (D69)		Ľ.	RTD[1] (D68)	_	R	RTD[0] (D67)		Ж	RTC[2] (D66)		ч	RTC[1] (D65)	
ш	0	OTA[4] (D74)		0	OTA[3] (D73)	(0	OTA[2] (D72)		О	OTA[1] (D71))	OTA[0] (D70)	
	0	OTB[4] (D79)		0	OTB[3] (D78)		0	OTB[2] (D77)		O	OTB[1] (D76))	OTB[0] (D75)	
Н	0	OTC[4] (D84)		0	ОТС[3] (D83)		0	OTC[2] (D82)		0	OTC[1] (D81)		0	OTC[0] (D80)	
Н	_	T4C[4] (D89)		L	T4C[3] (D88)		_	T4C[2] (D87)		T	T4C[1] (D86)			T4C[0] (D85)	
	-	T1C[4] (D94)		_	T1C[3] (D93)		-	T1C[2] (D92)		_	T1C[1] (D91)			T1C[0] (D90)	
	TC	тснот[2] (D99)	(6	TC	тснот[1] (D98)	8)	TC	тснот[0] (D97)	(2	T	T1C[6] (D96)			T1C[5] (D95)	
H	SP,	SPARE bit (D104)	14)	SP,	SPARE bit (D103))3)	TC	тснот[3] (D102)	2)	TCC	TCCOLD[1] (D101)	01)	TCC	rccolp[0] (D100)	(1
	RES	RESERVED (D109)	(60	RES	RESERVED (D108)	(80)	RES	RESERVED (D107)	07)	RES	RESERVED (D106)	(90	SP,	SPARE bit (D105))
	RES	RESERVED (D114)	14)	SET	SETTHRESH (D113)	113)	RES	RESERVED (D112)	12)	RES	RESERVED (D111)	11)	RES	RESERVED (D110)))
	RES	RESERVED (D119)	19)	RES	RESERVED (D118)	18)	RES	RESERVED (D117)	17)	RES	RESERVED (D116)	16)	RES	RESERVED (D115)	5)
	RES	RESERVED (D124)	24)	RES	RESERVED (D123)	(23)	RES	RESERVED (D122)	22)	RES	RESERVED (D121)	21)	RES	RESERVED (D120)	((
	RES	RESERVED (D129)	29)	RES	RESERVED (D128)	(28)	RES	RESERVED (D127	27)	RES	RESERVED (D126)	26)	RES	RESERVED (D125)	5)
\vdash	SP,	SPARE bit (D134)	14)	SP,	SPARE bit (D133)	33)	SP	SPARE bit (D132)	(2)	RES	RESERVED (D131)	31)	RES	RESERVED (D130))
\blacksquare	CRC	CRC10 [04] (D139)	39)	CRC	CRC10 [03] (D138)	38)	CRC	CRC10 [02] (D137)	37)	CRC	CRC10 [01] (D136)	36)	CR	CRC10 [00] (D135))
_	CRC	CRC10 [09] (D144)	44)	CRC	CRC10 [08] (D143)	43)	CRC	CRC10 [07] (D142)	12)	CRC	CRC10 [06] (D141)	41)	CR	CRC10 [05] (D140))

Table 2.3: ASIC Setting Parameters (EEPROM Memomry Map)

ASIC Description

SGE: Gain Range Select (2bits)

The "SGE" parameter selects the sensitivity of the current transducer. The V_{out} of the transducer will be $V_{ref} \pm 0.8$ V when its primary current is "± (each range value)".

Setting da	ata (2bits)	
SGE [1] (D41)	SGE[0] (D42)	Behaviour
0	0	25A range (default)
0	1	15A range
1	0	8A range
1	1	setting disable

RS: Reference Select (2bits)

The "RS" parameter selects the reference output voltage : V_{sol} of the transducer.

Setting da	ata (2bits)	
RS[1] (D43)	RS[0] (D42)	Behaviour
0	0	V _{ref} = 2.5V (default)
0	1	V _{ref} = 1.65 V
1	0	V _{ref} = 1.5 V
1	1	V _{ref} = 0.5 V

DVR Disable Vref output (1bit)

The "DVR" parameter selects enable or disable the output of the $V_{\rm ref}$. This transducer outputs the reference voltage from $V_{\rm ref}$ terminal. You can disconnect the internal reference of the ASIC and V_{ref} terminal by this parameter.

Setting data (1bits) DVR [0] (D44)	Behaviour
0	V _{ref} output : enabled (default)
1	V _{ref} output : disabled

SF Set output filter band width (2bits)

The "SF" parameter selects the cut-off frequency of the output filter of the transducer. You can select the cut-off frequency by changing this parameter.

You can reduce the noise level by selecting lower cut-off frequency but the response time will be longer at the same time.

Setting da	ata (2bits)	
SF[1] (D46)	SF[0] (D45)	Behaviour
0	0	No filter
0	1	fc = 600kHz (default)
1	0	fc = 250kHz
1	1	fc = 100kHz

ASIC Description

STE Threshold level select (3bits)

HO-NPPR Application Note

The "STE" parameter selects the over current detection level. The over current detection : OCD terminal (pin #5) will be forced to 'Low-level' (internal open-drain-circuit turns to ON) when the primary current exceeds the value (peak) of ratio which are shown in the following list.

SET THRESH Threshold level range select (1bit)

The "SET THRESH" parameter selects the OCD range. This parameter should be used in combination with the parameter "STE" above (See the list below).

s	Setting data (3bits	:)	SET THRESH se	SET THRESH setting data (1 bit)		
	ourig data (obit	,	SET THRE	SH (D113)		
STE [2] (D49)	STE[1] (D48)	STE[0] (D48)	8A, 15A range:1 25A range:0	25A range:1 * (25A range only)		
0	0	0	$1.7 \times I_{\rm PN}$	0.68 x I _{PN}		
0	0	1	$2.3 \times I_{\rm PN}$	0.93 x I _{PN}		
0	1	0	$2.9 \times I_{\rm PN}$	1.17 x I _{PN}		
0	1	1	$3.6 \times I_{\rm PN}$	1.4 x I _{PN}		
1	0	0	$4.0 \times I_{\rm PN}$	1.6 x I _{PN}		
1	0	1	$4.8 \times I_{\rm PN}$	1.9 x I _{PN}		
1	1	0	$5.2 \times I_{\rm PN}$	2.1 x I _{PN}		
1	1	1	$5.8 \times I_{\rm PN}$	2.3 x I _{PN}		

^{*}The ratios in the right side of the list are available at 25A range only.

TDT Threshold Detect Time (1bits)

The "TDT" parameter selects the response time of the OCD signal. It specifies the number of internal clock of the ASIC from the over current detection to the OCD signal output.

Setting data (1bits) TDT (D51)	Behaviour
0	ASIC internal clock x 2 (default)
1	ASIC internal clock x 3

TSS Threshold Signal Select (1bits)

The "TSS" parameter selects the pulse width of the OCD signal.

Setting data (1bits)	Behaviour
TSS (D52)	Deliavioui
0	1 ms (default)
1	10 us

Serial Communication

ARF Allow Ready/Fail action (1bits)

The "ARF" parameter selects the behavior of when memory error occurred at power-ON. If there is a difference between the computed CRC-10 value from all of the setting data and the stored CRC-10 value (address 27 and 28) in the EEPROM, the output of current transducer: Vout will be forced to 0V at ARF = 1. If "ARF" is set as "0", the $V_{\rm out}$ operates normally and it does not notify the occurrence of the error.

Setting data (1bits)	Behaviour	
ARF (D50)		
0	V _{out} operates normally even if memory error occured	
1	V _{out} is forced to 0V when memory error occured (default)	

3. Serial communication

3.1 Overview

The ASIC in the HO series current transducer shifts into a communication mode by connecting the V_{ref} terminal to U_{c} terminal (power-supply voltage). The data is sent or received through V_{out} terminal.

3.2 Timing chart

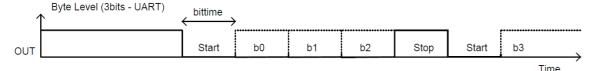
The ASIC has an UART (Universal Asynchronous Receiver Transmitter) and it operates with the following specification.

bit-rate 10k bit/sec

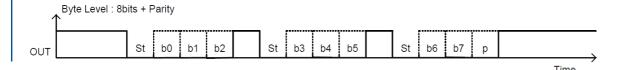
data structure "start" 1bit + "data" 3bits + "stop" 1bit

parity

The timing chart is shown below.

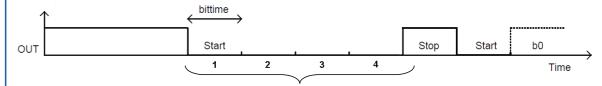


The 8 bits data (b0 to b7) are restructured as 9 bits by adding parity bit. They are divided into every 3 bits and are sent in order from LSB (See 'WriteByte' and 'WriteBit' function in the sample program).



Serial Communication

The communication bit-rate is adjusted by first received initial synchronization pulse automatically. Therefore, it is necessary to create and send the synchronization pulse (start (0)x4bits + stop(1)x1bit) before you send commands of the ASIC when you start the communication (see 'SynchMode' function in the sample program).



Synchronization pulse (start (0)x4bits + stop (1)x1bit)

3.3 Command list

HO-NPPR Application Note

The following table shows the command list of the ASIC (The value is given in hexadecimal).

	1Byte (8bits)	1Byte (8bits)	1Byte (8bits)	_
NOP				<u> </u>
mosi	00h			
miso				
READ_E	Ē			_
mosi	40h + addr			
miso		D[7:0]	D[15:8]	
READ_R	AM			
mosi	60h + addr			*Received data is added
miso		11Xb, D[4:0] @addr + 1	11Xb, D[4:0] @addr + 1	"11Xb" in its MSB (X is indefinite)
WRITE/EI	RASE_EE			
mosi	80h + addr	D[7:0]	D[15:8]	*Wait 5 ms before any
miso				other commands.
WRITE_R	RAM			
mosi	C0h + addr	000b, D[4:0]		*Send data must be
miso				added "00b" in its MSB
Continuo	us WRITE_RAM			
mosi	C0h + addr	100b, D[4:0] @ addr	100b, D[4:0] @ addr + 1	000b, D[4:0] @ addr
miso				Send data must be added "100b" in its MSB, and last send data must be added "000b" in its MSB

^{*}addr: The address of the memory

ded	Table 3.1: ASIC serial
ny	communication command list
e SB	
e S lata o" in	

Serial Communication

The value of "addr" must be from 0 to 31 for EEPROM and must be from 0 to 28 for RAM. Wait 5ms before sending any other commands after writing to EEPROM.

The data length in the RAM is 5bits, therefore you need to create the data as 8bits by adding "000"(binary) in its MSB when you send 'WRITE RAM' command. (add "100" when you send 'Continuous WRITE RAM' command.)

The received data by 'READ_RAM' command has "11X" (binary, X is indefinite) in its MSB and the 5bits from LSB is actual data.

3.4 Communication Procedure

The ASIC in the HO series current transducer shifts into a communication mode by connecting the V_{con} terminal to U_c terminal (power-supply voltage) as described above. The data is sent or received through Vout terminal.

The actual waveforms of following procedure are shown below.

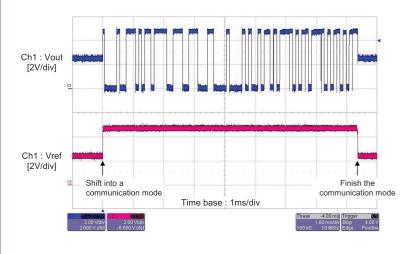


Fig 3.1: **ASIC** serial communication waveform

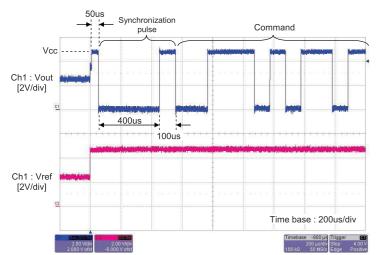


Fig 3.2: **ASIC** serial communication waveform (zoom)

Implementation Example on Arduino

- (1) Shift into a communication mode by connecting $V_{\rm ref}$ terminal to $U_{\rm c}$.
- (2) Wait 50 µs.

HO-NPPR Application Note

- (3) Send the synchronization pulse (start (0)x4bits + stop(1)x1bit) to V_{out} terminal.
- (4) Send and Receive command data
- (4.1) Send 'UNLOCK' command (EEh,36h)
- (4.2) Send 'READ_EE' command of EEPROM address:0 (40h + 0 (address))
- (4.3) Read data from ASIC (8bit x 2 : D[7:0], D[15:8])
- (5) Finish the communication mode by disconnecting $V_{\rm enf}$ terminal from $U_{\rm c}$.

4. Implementation example on Arduino

4.1 Overview

"Arduino" is a general-purpose microcomputer system which contains a PCB with Atmel AVR processor with I/O ports and IDE (integrated development environment).

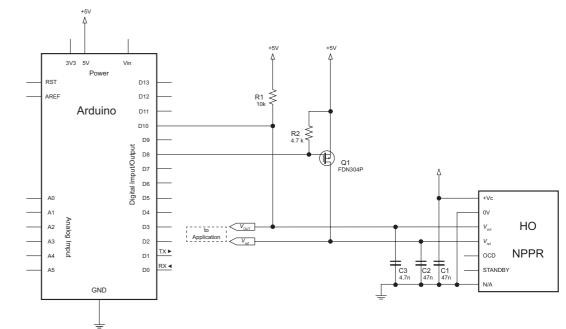
IDE is freely available on various platforms (Windows, Mac OS X, Linux), and it can be downloaded from "http://arduino.cc/".

This chapter introduces you to the system structure and sample programs which changing the setting of the HO series current transducer.

(Regarding the set-up of IDE of Arduino and so on, please refer the website above or other related documents.)

- Confirmed boards
- Arduino UNO board
- Arduino NANO board

4.2 Schematics



Implementation Example on Arduino

In this example, D8 pin is assigned as a control of V_{ref} terminal (ON/OFF of the communication mode) and D10 pin is assigned as data signal line (send and receive of command data).

4.3 Sample program

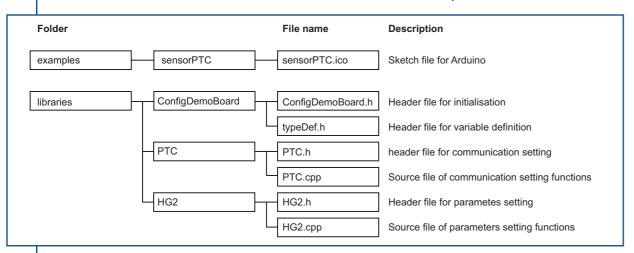
You can operate the program which changes the setting of HO series transducer using this sample program with the example schematics in 4.2.

The sample program contains dedicated functions for Arduino microcontroller for setting of serial communication procedure, memory address and so on which are explained in chapter 2 and 3. It allows for changing the HO series transducer configuration by only executing 'update memory function' with setting parameters and memory definition (RAM or EEPROM).

4.3.1 List of sample program

Structure of the sample program provided for Arduino boards is shown below.

"sensorPTC.ico" is a main source file for Arduino board and it operates with included each



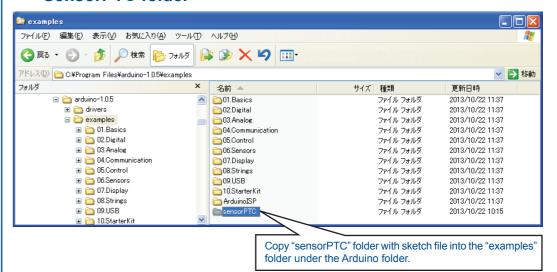
header files and source files of functions.

When you operate the sample program, please copy the sketch file to the "examples" folder, and copy the header/source file with subfolders to the "libraries" folder.

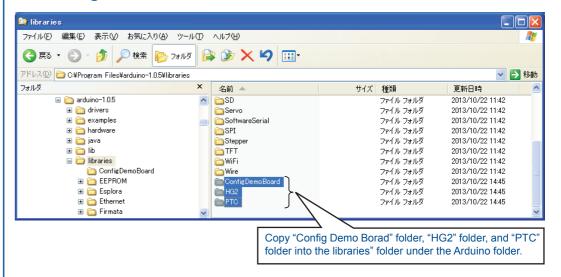
Implementation Example on Arduino

SensorPTC folder

HO-NPPR Application Note



ConfigDemoBoard HG2 PTC folder



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Implementation Example on Arduino

4.3.2 List of parameters and functions

Parameters and functions defined in this sample program are shown below. You can change the setting of HO series transducer by updating setting data in the EEPROM or RAM with these parameters and functions.

Memory definition

RAM Select "RAM" of the ASIC in HO series as an operating object **EEPROM** Select "EEPROM" of the ASIC in HO series as an operating object

- Definition (PTC.h)

```
typedef enum {
       RAM.
       FFPROM
       EXT RAM
                       ( <- Not used )
} Memory_e;
```

Setting parameter's name

```
SGE_REG
                         Select SGE setting parameter (Gain Range Select; 2bits)
RS REG
                         Select RS setting parameter (Reference Select; 2bits)
DVR REG
                         Select DVR setting parameter (Disable Vref output; 1bit)
SF REG
                         Select SF setting parameter (Set output filter band width; 2bits)
STE REG
                         Select STE setting parameter (Threshold level select; 3bits)
```

SET_THRESH_REG Select SET THRESH setting parameter (Threshold level range select; 1bit)

TDT REG Select TDT setting parameter (Threshold Detect Time; 1bits) TSS_REG Select **TSS** setting parameter (Threshold Signal Select; 1bits) ARF_REG Select ARF setting parameter (Allow Ready/Fail action; 1bits)

- Definition (HG2.h)

```
typedef enum {
      GA_REG
                            // Gain set A - 12 bits
                                                                   ( <- Not used )
      GB_REG,
                            // Gain set B - 12 bits
                                                                   ( <- Not used )
                            // Gain set C - 12 bits
      GC_REG,
                                                                   ( <- Not used )
      SGE REG,
                            // Gain range Select - 2 bits
      RS REG,
                            // Reference Select - 2 bits
      DVR_REG,
                            // Disable Vref output - 1 bit, 0=output enabled
      SF REG.
                            // Set output Filter bandwidth - 2 bits
      STE_REG,
                            // Threshold level Select - 3 bits - only applicable for SOIC-8 package
      SET_THRESH_REG, // Set Threshold High or Low Range - 1 bit
      TDT REG,
                            // Threshold detect time - 1 bit
      TSS REG
                            // Threshold Signal Select - 1 bit
      ARF_REG,
                            // Allow ready/fail action - 1 bit, 0=not active
      TC4_REG
                            // Offset drift, 1rst order - 5 bits
                                                                   ( <- Not used )
      TC1 REG
                                                                   ( <- Not used )
                            // 1rst order gain TC - 7 bits
  } ParamHG2 e;
```

Implementation Example on Arduino

Function list

HO-NPPR Application Note

RetrieveMemory

A function of activating the memory of ASIC in HO series. It is necessary to execute before you operate each memories.

Input: Type of memory (RAM or EEPROM)

Output: Return the status == 0 (OK), 1 (Reading parity error), 2 (Failed)

```
Name: void RetrieveMemory (Memory_e e_type)
   Description
             - Get current Memory configuration
              This function must be used at the first of each new setting
             (ie: use of SetParam function)
   Input
             - Memory_e e_type:
                                               Memory type
   Output:
             - Return the status:
                                    0 (OK),1 (Reading Parity Error), 2 (Failed)
   Called by:
   Called Modules
   References
             - none
```

GetParam

A function of reading current setting parameter's value of HO series.

Input: Name of setting parameter (SGE REG, RS REG, and so on)

: Type of memory (RAM or EEPROM)

Output: Value of setting parameter (unsigned integer)

```
Name: U16 GetParam (ParamHG2_e eParam, Memory_e e_type)
           - Get Param from Memory (RAM | EEPROM | EXTENDED RAM)
   Input
           - ParamHG2 e eParam: Configurable register
            - Memory_e e_type:
                                  Memory type
   Output
                                  Register value
   Called by:
   Called Modules
   References
```

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Implementation Example on Arduino

SetParam

A function of sending each setting parameter's value to memory in the ASIC.

Input: Name of setting parameter (SGE_REG, RS_REG, and so on)

: The value of the setting parameter (unsigned integer)

: Type of memory (RAM or EEPROM)

Output: None

```
Name: U16 SetParam (ParamHG2_e eParam, U16 u16Value, Memory_e e_type)

Description:
- Set Param in Memory (RAM | EEPROM | EXTENDED RAM)

Input:
- ParamHG2_e eParam: Configrable register
- U16 u16Value: Register value to be set
- Memory_e e_type: Memory type

Output:
- none

Called by:
Called Modules:
References:
- none
```

UpdateMemory

A function of updating the memory.

The defined memory (RAM or EEPROM) will be updated with calculated CRC-10 value after you send a setting parameter's value by SetParam function.

Please note that the memory data will not be updated unless you execute this UpdateMemory function.

Input: Type of memory (RAM or EEPROM)

Output: None

```
Name: void UpdateMemory (Memory_e e_type)

Description:

- Update Memory with the current configuration
This function must be used at the end of each new setting
(ie: use of SetParam function)

Input:

- Memory_e e_type : Memory type

Output:
- none

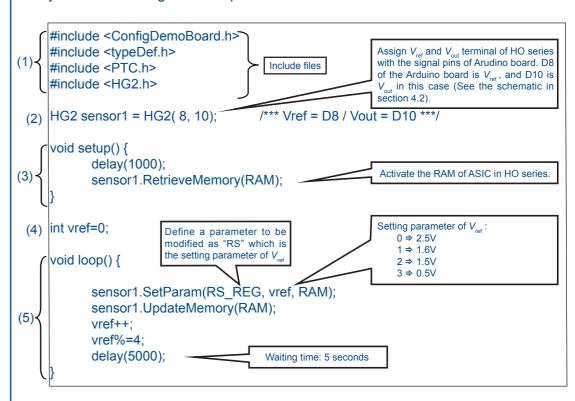
Called by:
Called Modules:
References:
- none
```

Implementation Example on Arduino

4.3.3 Explanation of sample program: sensorPTC

Explanation of the sample program "sensorPTC" is shown below.

This program switches the Vref setting of HO series as $(2.5V \Rightarrow 1.6V \Rightarrow 1.5V \Rightarrow 0.5V)$ in every 5 seconds using the example schematics in section 4.2.



- Include each header files.
- (2) Assign $V_{\rm ref}$ terminal of HO with D8 of Arduino board, and $V_{\rm out}$ with D10 based on the schematic in section 4.2 .¹⁾
- (3) Wait 1 second (1000ms), and activate the RAM of ASIC in HO by executing "RetrieveMemory" function.
- (4) Declare a variable "vref" and initialize it in "0"
- (5) Loop function (Repetitive function)
- (5.1) Define "RS REG" parameter with 'SetParam' function and define its value as "vref".
- (5.2) Update the value in the RAM with 'UpdateMemory' function. \Rightarrow The V_{ref} setting of the HO series switches.
- (5.3) Add "1" to the variable "vref", and substitute the remainder of dividing it by 4 to the "vref".
- (5.4) Wait 5 seconds (5000ms) and go back to the (5.1).
- 1) The class named "HG2" is declared in the header file "HG2.h".

This line declares the object named "sensor1" of "HG2" class and assigns its initial values as its argument which define pin assignment information.

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HO-NPPR Application Note

Appendix

5 Appendix

5.1 HO 25-NPPR Initial value of setting parameters

Parameter Name	Value	Behaviour	
SGE	0	Primary nomial current: I _{PN} = 25A range	
RS	0	Internal reference voltage: V _{ref} = 2.5V	
DVR	0	Internal reference voltage output: V_{ref} out is enabled	
SF	1		
STE	2	COD data disconsiste and Cod	
SET_THRESH	0	OCD detection value = 2.9x I _{PN}	
TDT	0	OCD detection time: ASIC internal clock x 2 (1.3 μs)	
TSS	0	OCD output pulse width : 1 ms	
ARF	1	V _{out} is forced to 0V when memory error occured	